<u>Voltage Regulator</u> - High Accuracy, Ultra Low Iq, Adjustable, Low Dropout 500 mA

The NCP3334 is a high performance, low dropout regulator. With accuracy of $\pm 0.9\%$ over line and load and ultra-low quiescent current and noise it encompasses all of the necessary features required by today's consumer electronics. This unique device is guaranteed to be stable without a minimum load current requirement and stable with any type of capacitor as small as $1.0 \ \mu\text{F}$. The NCP3334 offers reverse bias protection.

Features

- High Accuracy Over Line and Load (±0.9% at 25°C)
- Ultra-Low Dropout Voltage
- Low Noise
- Low Shutdown Current (0.07 μA)
- Reverse Bias Protected
- 2.6 V to 12 V Supply Range
- Thermal Shutdown Protection
- Current Limitation
- Requires Only 1.0 µF Output Capacitance for Stability
- Stable with Any Type of Capacitor (including MLCC)
- No Minimum Output Current Required for Stability
- This is a Pb–Free Device

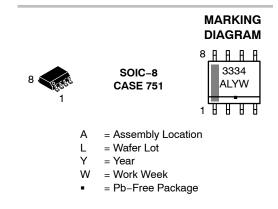
Applications

- PCMCIA Card
- Cellular Phones
- Camcoders and Cameras
- Networking Systems, DSL/Cable Modems
- Cable Set-Top Box
- MP3/CD Players
- DSP Supply
- Displays and Monitors



ON Semiconductor®

http://onsemi.com



PIN CONNECTIONS

	1 -		. 8	
GND	è	0	۔	NC
SD	며		╘	FB
IN	━			OUT
IN	╓┥		╞╍	OUT
	L	1		

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

1

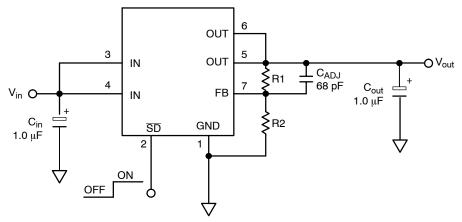


Figure 1. Typical Adjustable Version Application Schematic

PIN FUNCTION DESCRIPTION

Pin No.	Pin Name	Description
1	GND	Power Supply Ground
2	SD	Shutdown pin. When not in use, this pin should be connected to the input pin.
3, 4	IN	Power Supply Input Voltage
5, 6	OUT	Regulated output voltage. Bypass to ground with $C_{out} \ge 1.0 \ \mu\text{F}.$
7	FB	Feedback pin; reference voltage = 1.25 V.
8	NC	Not Connected

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage		–0.3 to +16	V
Output Voltage	Vout	–0.3 to V _{in} +0.3 or 10 V*	V
Shutdown Pin Voltage	V _{sh}	–0.3 to +16	V
Thermal Characteristics Thermal Resistance, Junction-to-Air	$R_{ hetaJA}$	238	°C/W
Operating Junction Temperature Range	TJ	-40 to +150	°C
Storage Temperature Range	T _{stg}	-50 to+150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

NOTE: This device series contains ESD protection and exceeds the following tests:

Human Body Model (HBM) JESD 22-A114-B

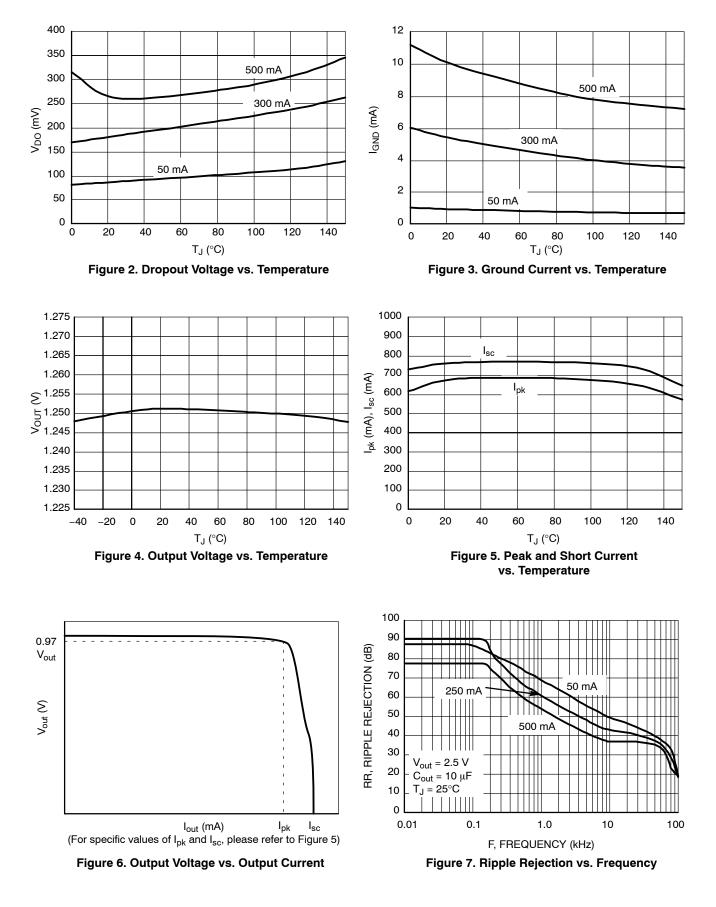
Machine Model (MM) JESD 22-A115-A

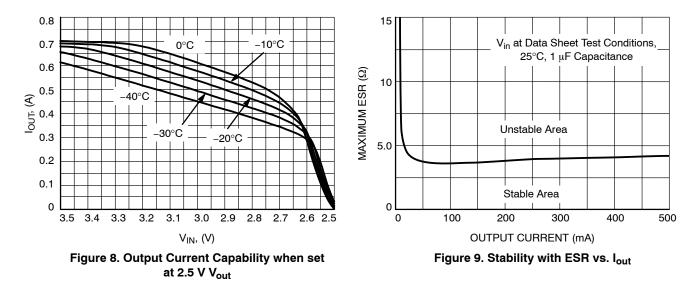
*Whichever is less. Reverse bias protection feature valid only if V_{out} – V_{in} \leq 7.0 V.

ELECTRICAL CHARACTERISTICS (Vout = 1.25 V (V_{ref}) typical, $V_{in} = 2.9 \text{ V}$, $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, unless otherwise noted.)
---	---

Characteristic	Symbol	Min	Тур	Max	Unit
Reference Voltage Accuracy V_{in} = 2.9 V to V _{out} + 4.0 V, I _L = 0.1 mA to 500 mA, T _A = 25°C	V _{REF}	-0.9% 1.239	1.25	+0.9% 1.261	V
Reference Voltage Accuracy V_{in} = 2.9 V to V _{out} + 4.0 V, I _L = 0.1 mA to 500 mA, T _A = 0°C to +85°C	V _{REF}	-1.4% 1.233	1.25	+1.4% 1.268	V
Reference Voltage Accuracy (Note 1) V_{in} = 2.9 V to V _{out} + 4.0 V, I _L = 0.1 mA to 500 mA, T _A = -40°C to +150°C	V _{REF}	-1.5% 1.231	1.25	+1.5% 1.269	V
Line Regulation V_{in} = 2.9 V to 12 V, I _L = 0.1 mA	Line _{Reg}		0.04		mV/V
Load Regulation V_{in} = 2.9 V, I _L = 0.1 mA to 500 mA	Load _{Reg}		0.04		mV/mA
Dropout Voltage, $V_{out} = 2.5 V$ to 10 V $I_L = 500 \text{ mA} \text{ (Note 2)}$ $I_L = 300 \text{ mA}$ $I_L = 50 \text{ mA}$ $I_L = 0.1 \text{ mA}$	V _{Drop}			340 230 110 10	mV
Peak Output Current (Notes 1 and 2) (See Figure 6)	lpk	500	700	860	mA
Short Output Current (See Figure 6) $V_{out} \le 3.3 \text{ V} \\ V_{out} > 3.3 \text{ V}$	I _{sc}		990	900 1300	mA
Thermal Shutdown	T _{JSD}		160		°C
Ground Current In Regulation $I_L = 500 \text{ mA} \text{ (Note 2)}$ $I_L = 300 \text{ mA} \text{ (Note 2)}$ $I_L = 50 \text{ mA}$ $I_L = 0.1 \text{ mA}$	I _{GND}		9.0 4.6 0.8 -	14 7.5 2.5 190	mA μA
In Dropout $V_{in} = V_{out} -0.1 \text{ V}, I_L = 0.1 \text{ mA}$			-	500	μΑ
In Shutdown V _{SD} = 0 V	I _{GNDsh}		0.07	1.0	μΑ
Output Noise IL = 500 mA, f = 10 Hz to 100 kHz, C _{out} = 10 μ F	V _{noise}		38		μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF	V _{THSD}	2.0		0.4	V V
\overline{SD} Input Current, V_{SD} = 0 V to 0.4 V or V_{SD} = 2.0 V to V_{in} $$V_{in} \le 5.4 \ V_{in} > 5.4 \ V$	I _{SD}		0.07	1.0 5.0	μΑ
Output Current In Shutdown Mode, V _{out} = 0 V	I _{OSD}		0.07	1.0	μΑ
Reverse Bias Protection, Current Flowing from the Output Pin to GND (V _{in} = 0 V, V _{out_forced} = V _{out} (nom) ≤ 7 V) (Note 3)			1.0		μΑ
RECOMMENDED OPERATING CONDITIONS			-	-	-
Input Voltage	V _{IN}	2.6		12	V

1. For output current capability for $T_J < 0^{\circ}C$, please refer to Figure 8. 2. T_A must be greater than $0^{\circ}C$. 3. Reverse bias protection feature valid only if $V_{out} - V_{in} \le 7.0 \text{ V}$.





APPLICATIONS INFORMATION

Reverse Bias Protection

Reverse bias is a condition caused when the input voltage goes to zero, but the output voltage is kept high either by a large output capacitor or another source in the application which feeds the output pin.

Normally in a bipolar LDO all the current will flow from the output pin to input pin through the PN junction with limited current capability and with the potential to destroy the IC.

Due to an improved architecture, the NCP3334 can withstand up to 7.0 V on the output pin with virtually no current flowing from output pin to input pin, and only negligible amount of current (tens of μ A) flowing from the output pin to ground for infinite duration.

Operation with output voltages in the range of 7 to 10 volts requires that the output to input voltage differential be less than 7 volts.

Input Capacitor

An input capacitor of at least 1.0 μ F, any type, is recommended to improve the transient response of the regulator and/or if the regulator is located more than a few inches from the power source. It will also reduce the circuit's sensitivity to the input line impedance at high frequencies. The capacitor should be mounted with the shortest possible track length directly across the regulator's input terminals.

Output Capacitor

The NCP3334 remains stable with any type of capacitor as long as it fulfills its 1.0 μ F requirement. There are no constraints on the minimum ESR and it will remain stable up to an ESR of 5.0 Ω . Larger capacitor values will improve the noise rejection and load transient response.

Noise Reduction

A 68 pF capacitor connected in parallel with R1 (see Figure 1) is recommended to reduce output noise and improve stability.

Adjustable Operation

The output voltage can be set by using a resistor divider as shown in Figure 1 with a range of 1.25 to 10 V. The appropriate resistor divider can be found by solving the equation below. The recommended current through the resistor divider is from 10 μ A to 100 μ A. This can be accomplished by selecting resistors in the k Ω range. As result, the I_{adj}*R2 becomes negligible in the equation and can be ignored.

$$V_{out} = 1.25 * \left(1 + \frac{R1}{R2}\right) + I_{adj} * R2$$
 (eq. 1)

Example:

For $V_{out} = 2.9$ V, can use $R_1 = 36$ k Ω and $R_2 = 27$ k Ω .

$$1.25 * \left(1 + \frac{36 \text{ k}\Omega}{27 \text{ k}\Omega}\right) = 2.91 \text{ V}$$
 (eq. 2)

Dropout Voltage

The voltage dropout is measured at 97% of the nominal output voltage.

Thermal Considerations

Internal thermal limiting circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. This feature provides protection from a catastrophic device failure due to accidental overheating. This protection feature is not intended to be used as a substitute to heat sinking. The maximum power that can be dissipated, can be calculated with the equation below:

$$P_{D} = \frac{T_{J}(max) - T_{A}}{R_{\theta JA}}$$
 (eq. 3)

For improved thermal performance, contact the factory for the DFN package option. The DFN package includes an exposed metal pad that is specifically designed to reduce the junction to air thermal resistance, $R_{\theta JA}$.

ORDERING INFORMATION

Device	Package	Shipping [†]
NCP3334DADJG	SO-8 (Pb-Free)	98 Units / Rail
NCP3334DADJR2G	SO–8 (Pb–Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

The products described herein NCP3334, may be covered by one or more of the following U.S. patents; 5,920,184, 5,966,004, and 5,834,926. There may be other patents pending.

Micro8 is a trademark of International Rectifier.

onsemí



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

DOCUMENT NUMBER:	98ASB42564B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	SOIC-8 NB		PAGE 1 OF 2		
the right to make changes without furth purpose, nor does onsemi assume ar	onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.				

SOIC-8 NB CASE 751-07 **ISSUE AK**

STYLE 1: PIN 1. EMITTER COLLECTOR 2. 3. COLLECTOR 4. EMITTER 5. EMITTER BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. DRAIN 8. STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT IOUT 6. IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3 P-SOURCE P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE ANODE 2. SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. CATHODE 8. STYLE 22 PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC 4. I/O LINE 3 COMMON ANODE/GND 5. 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4 SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5.

6.

7.

8 GATE 1

SOURCE 1/DRAIN 2

STYLE 3: PIN 1. DRAIN, DIE #1 DRAIN, #1 2. DRAIN, #2 З. DRAIN, #2 4. GATE, #2 5. SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. З. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 ANODE 1 3 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 MIRROR 1 8. STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. 8. LINE 1 OUT STYLE 27: PIN 1. ILIMIT OVI O 2 UVLO З. 4. INPUT+ 5. 6. SOURCE SOURCE SOURCE 7. 8 DRAIN

DATE 16 FEB 2011

STYLE 4: PIN 1. 2. ANODE ANODE ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 З. BASE #2 COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. GATE 4. 5. DRAIN 6 DRAIN DRAIN 7. 8. DRAIN STYLE 16 EMITTER, DIE #1 PIN 1. 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE EMITTER 2. 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW_TO_GND 2. DASIC OFF DASIC_SW_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

DOCUMENT NUMBER:	98ASB42564B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	SOIC-8 NB		PAGE 2 OF 2		

onsem and of isor in are trademarks or semiconductor compension instructions, the do onsem or its subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced stat purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

7.

8

COLLECTOR, #1

COLLECTOR, #1

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>